## NSN 5961-01-109-7634

Transistor - Page 1 of 1

**Fiig:** A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-109-7634 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 0.10 amperes source cutoff current **Power Rating Per Characteristic:** 90.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli